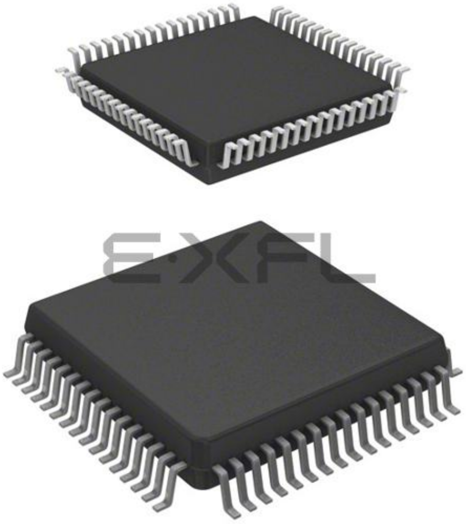
NXP USA Inc. - MKE02Z32VQH2 Datasheet



What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	20MHz
Connectivity	I²C, SPI, UART/USART
Peripherals	LVD, PWM, WDT
Number of I/O	57
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b; D/A 2x6b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-QFP
Supplier Device Package	64-QFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mke02z32vqh2

- Communication interfaces
  - Two SPI modules (SPI)
  - Up to three UART modules (UART)
  - One I2C module (I2C)
- Package options
  - 64-pin QFP/LQFP
  - 44-pin LQFP
  - 32-pin LQFP

Table of Contents

1 Ordering parts

1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to **nxp.com** and perform a part number search for the following device numbers: KE02Z.

2 Part identification

2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

2.2 Format

Part numbers for this device have the following format:

Q KE## A FFF R T PP CC N

2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	• M = Fully qualified, general market flow • P = Prequalification
KE##	Kinetis family	• KE02
A	Key attribute	• Z = M0+ core
FFF	Program flash memory size	• 16 = 16 KB • 32 = 32 KB • 64 = 64 KB
R	Silicon revision	• (Blank) = Main • A = Revision after main

Table continues on the next page...

4 Ratings

4.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T_{STG}	Storage temperature	–55	150	°C	1
T_{SDR}	Solder temperature, lead-free	—	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V_{HBM}	Electrostatic discharge voltage, human body model	–6000	+6000	V	1
V_{CDM}	Electrostatic discharge voltage, charged-device model	–500	+500	V	2
I_{LAT}	Latch-up current at ambient temperature of 125°C	–100	+100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78D, *IC Latch-up Test*.
    - Test was performed at 125 °C case temperature (Class II).
    - I/O pins pass ±100 mA I-test with I_{DD} current limit at 800 mA.
    - I/O pins pass +60/-100 mA I-test with I_{DD} current limit at 1000 mA.
    - Supply groups pass 1.5 V_{ccmax}.
    - $\overline{\text{RESET}}$ pin was only tested with negative I-test due to product conditioning requirement.

4.4 Voltage and current operating ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in the following table may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this document.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either V_{SS} or V_{DD}) or the programmable pullup resistor associated with the pin is enabled.

Table 2. Voltage and current operating ratings

Symbol	Description	Min.	Max.	Unit
V_{DD}	Digital supply voltage	–0.3	6.0	V
I_{DD}	Maximum current into V_{DD}	—	120	mA
V_{IN}	Input voltage except true open drain pins	–0.3	V_{DD} + 0.3[1]	V
	Input voltage of true open drain pins	–0.3	6	V
I_D	Instantaneous maximum current single pin limit (applies to all port pins)	–25	25	mA
V_{DDA}	Analog supply voltage	V_{DD} – 0.3	V_{DD} + 0.3	V

1. Maximum rating of V_{DD} also applies to V_{IN}.

5 General

5.1 Nonswitching electrical specifications

5.1.1 DC characteristics

This section includes information about power supply requirements and I/O pin characteristics.

Table 3. DC characteristics

Symbol	C	Descriptions		Min	Typical[1]	Max	Unit
—	—	Operating voltage	—	2.7	—	5.5	V

Table continues on the next page...

Table 3. DC characteristics (continued)

Symbol	C	Descriptions			Min	Typical[1]	Max	Unit
V_{OH}	P	Output high voltage	All I/O pins, except PTA2 and PTA3, standard-drive strength	5 V, I_{load} = –5 mA	V_{DD} – 0.8	—	—	V
	C			3 V, I_{load} = –2.5 mA	V_{DD} – 0.8	—	—	V
	P		High current drive pins, high-drive strength[2]	5 V, I_{load} = –20 mA	V_{DD} – 0.8	—	—	V
	C			3 V, I_{load} = –10 mA	V_{DD} – 0.8	—	—	V
I_{OHT}	D	Output high current	Max total I_{OH} for all ports	5 V	—	—	–100	mA
				3 V	—	—	–60	
V_{OL}	P	Output low voltage	All I/O pins, standard-drive strength	5 V, I_{load} = 5 mA	—	—	0.8	V
	C			3 V, I_{load} = 2.5 mA	—	—	0.8	V
	P		High current drive pins, high-drive strength[2]	5 V, I_{load} =20 mA	—	—	0.8	V
	C			3 V, I_{load} = 10 mA	—	—	0.8	V
I_{OLT}	D	Output low current	Max total I_{OL} for all ports	5 V	—	—	100	mA
				3 V	—	—	60	
V_{IH}	P	Input high voltage	All digital inputs	4.5≤V_{DD}<5.5 V	0.65 × V_{DD}	—	—	V
				2.7≤V_{DD}<4.5 V	0.70 × V_{DD}	—	—	
V_{IL}	P	Input low voltage	All digital inputs	4.5≤V_{DD}<5.5 V	—	—	0.35 × V_{DD}	V
				2.7≤V_{DD}<4.5 V	—	—	0.30 × V_{DD}	
V_{hys}	C	Input hysteresis	All digital inputs	—	0.06 × V_{DD}	—	—	mV
$\|I_{In}\|$	P	Input leakage current	Per pin (pins in high impedance input mode)	V_{IN} = V_{DD} or V_{SS}	—	0.1	1	µA
$\|I_{INTOT}\|$	C	Total leakage combined for all port pins	Pins in high impedance input mode	V_{IN} = V_{DD} or V_{SS}	—	—	2	µA
R_{PU}	P	Pullup resistors	All digital inputs, when enabled (all I/O pins other than PTA2 and PTA3)	—	30.0	—	50.0	kΩ
R_{PU}[3]	P	Pullup resistors	PTA2 and PTA3 pins	—	30.0	—	60.0	kΩ
I_{IC}	D	DC injection current[4, 5, 6]	Single pin limit	V_{IN} < V_{SS}, V_{IN} > V_{DD}	-2	—	2	mA
			Total MCU limit, includes sum of all stressed pins		-5	—	25	
C_{In}	C	Input capacitance, all pins		—	—	—	7	pF
V_{RAM}	C	RAM retention voltage		—	2.0	—	—	V

1. Typical values are measured at 25 °C. Characterized, not tested.
2. Only PTB4, PTB5, PTD0, PTD1, PTE0, PTE1, PTH0, and PTH1 support high current output.

3. The specified resistor value is the actual value internal to the device. The pullup value may appear higher when measured externally on the pin.
4. All functional non-supply pins, except for PTA2 and PTA3, are internally clamped to V_{SS} and V_{DD}. PTA2 and PTA3 are true open drain I/O pins that are internally clamped to V_{SS}.
5. Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger value.
6. Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If the positive injection current ($V_{In} > V_{DD}$) is higher than I_{DD}, the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure that external V_{DD} load will shunt current higher than maximum injection current when the MCU is not consuming power, such as when no system clock is present, or clock rate is very low (which would reduce overall power consumption).

Table 4. LVD and POR specification

Symbol	C	Description		Min	Typ	Max	Unit
V_{POR}	D	POR re-arm voltage[1]		1.5	1.75	2.0	V
V_{LVDH}	C	Falling low-voltage detect threshold—high range (LVDV = 1)[2]		4.2	4.3	4.4	V
V_{LVW1H}	C	Falling low-voltage warning threshold—high range	Level 1 falling (LVWV = 00)	4.3	4.4	4.5	V
V_{LVW2H}	C		Level 2 falling (LVWV = 01)	4.5	4.5	4.6	V
V_{LVW3H}	C		Level 3 falling (LVWV = 10)	4.6	4.6	4.7	V
V_{LVW4H}	C		Level 4 falling (LVWV = 11)	4.7	4.7	4.8	V
V_{HYSH}	C	High range low-voltage detect/warning hysteresis		—	100	—	mV
V_{LVDL}	C	Falling low-voltage detect threshold—low range (LVDV = 0)		2.56	2.61	2.66	V
V_{LVW1L}	C	Falling low-voltage warning threshold—low range	Level 1 falling (LVWV = 00)	2.62	2.7	2.78	V
V_{LVW2L}	C		Level 2 falling (LVWV = 01)	2.72	2.8	2.88	V
V_{LVW3L}	C		Level 3 falling (LVWV = 10)	2.82	2.9	2.98	V
V_{LVW4L}	C		Level 4 falling (LVWV = 11)	2.92	3.0	3.08	V
V_{HYSDL}	C	Low range low-voltage detect hysteresis		—	40	—	mV
V_{HYSWL}	C	Low range low-voltage warning hysteresis		—	80	—	mV
V_{BG}	P	Buffered bandgap output [3]		1.14	1.16	1.18	V

[1] Maximum is highest voltage that POR is guaranteed.

[2] Rising thresholds are falling threshold + hysteresis.

[3] voltage Factory trimmed at V_{DD} = 5.0 V, Temp = 25 °C

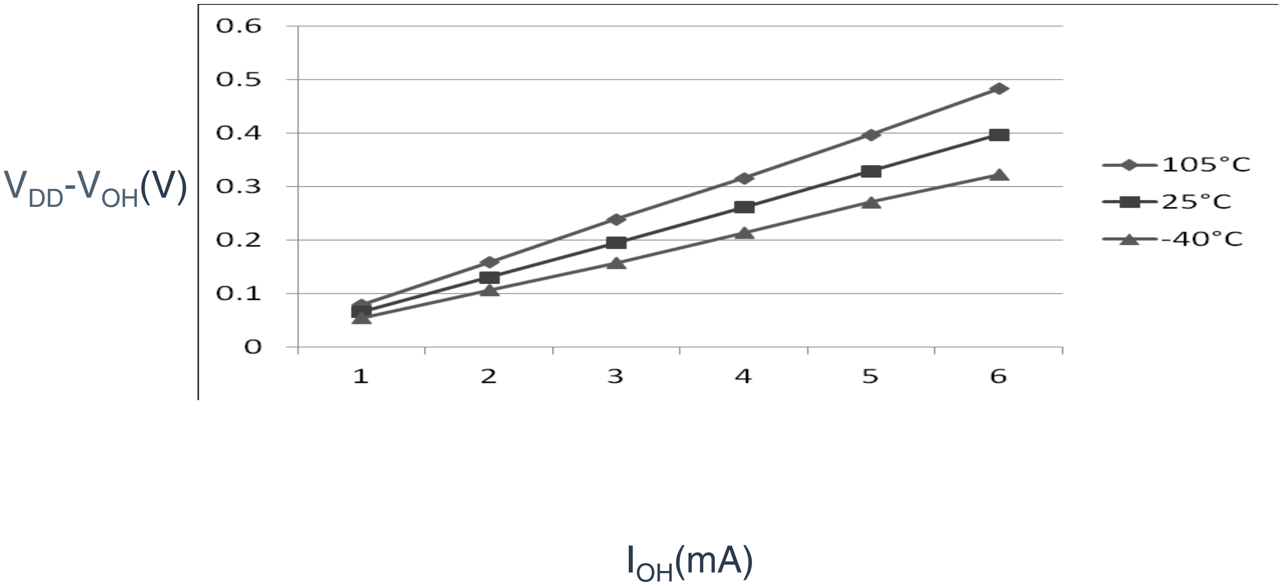


Figure 1. Typical V_{DD}-V_{OH} Vs. I_{OH} (standard drive strength) (V_{DD} = 5 V)

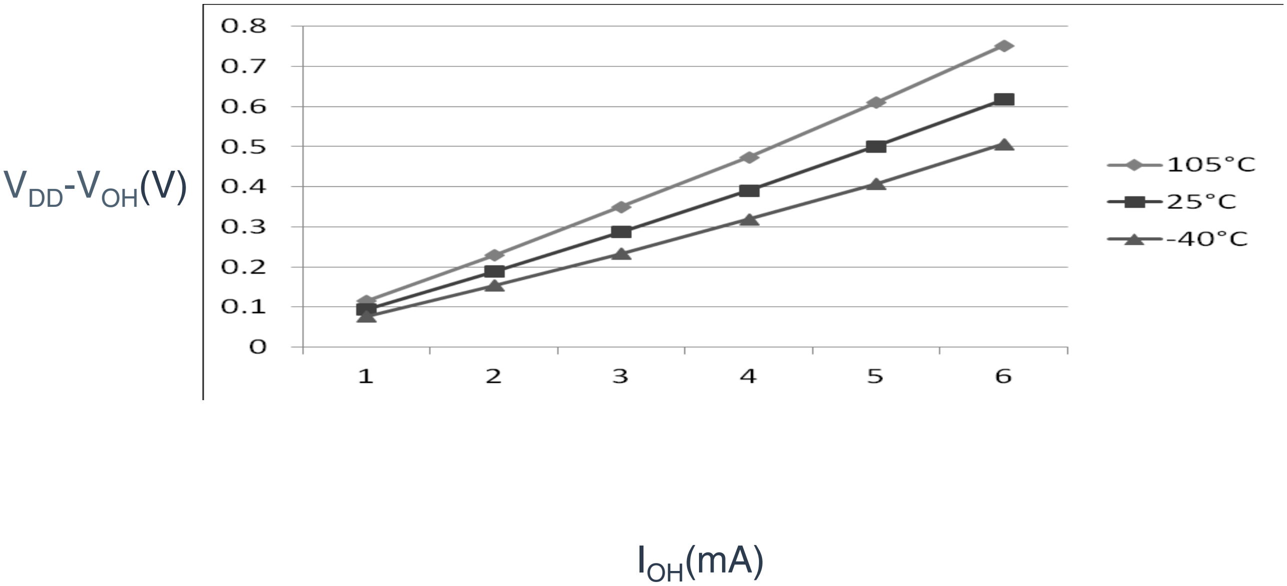


Figure 2. Typical V_{DD}-V_{OH} Vs. I_{OH} (standard drive strength) (V_{DD} = 3 V)

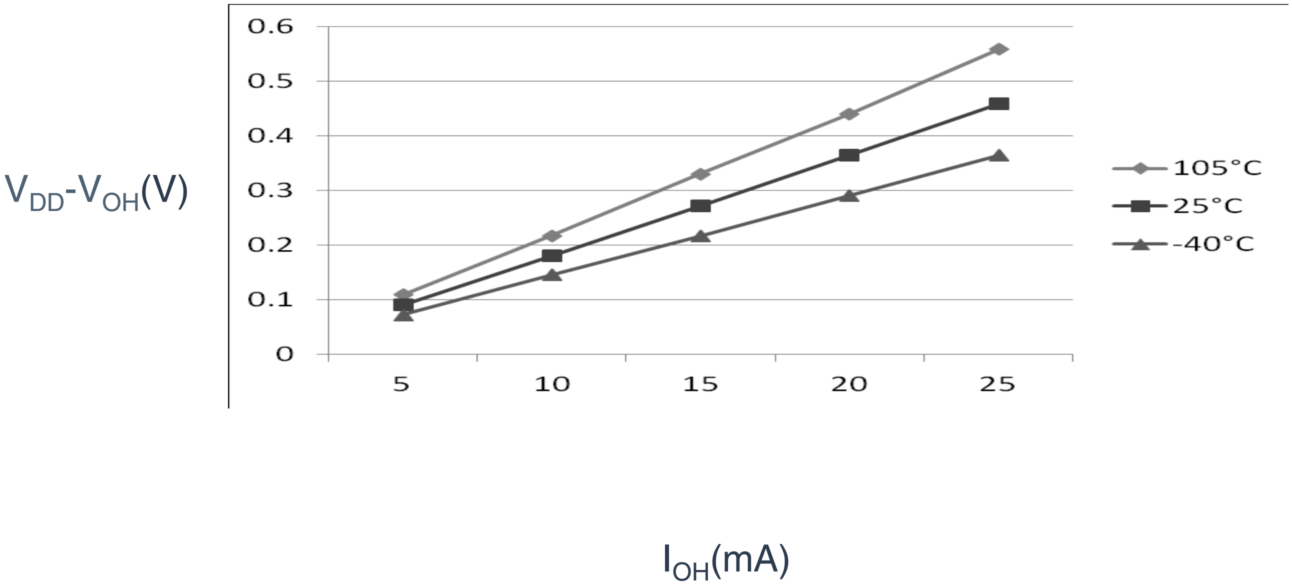


Figure 3. Typical V_{DD}-V_{OH} Vs. I_{OH} (high drive strength) (V_{DD} = 5 V)

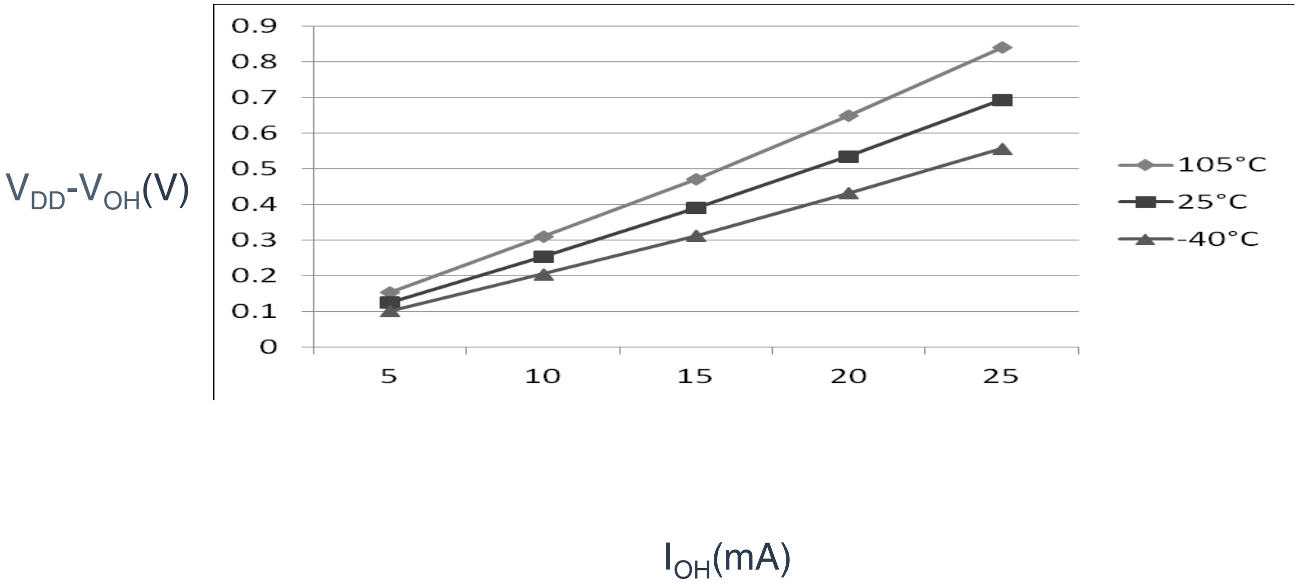


Figure 4. Typical V_{DD}-V_{OH} Vs. I_{OH} (high drive strength) (V_{DD} = 3 V)

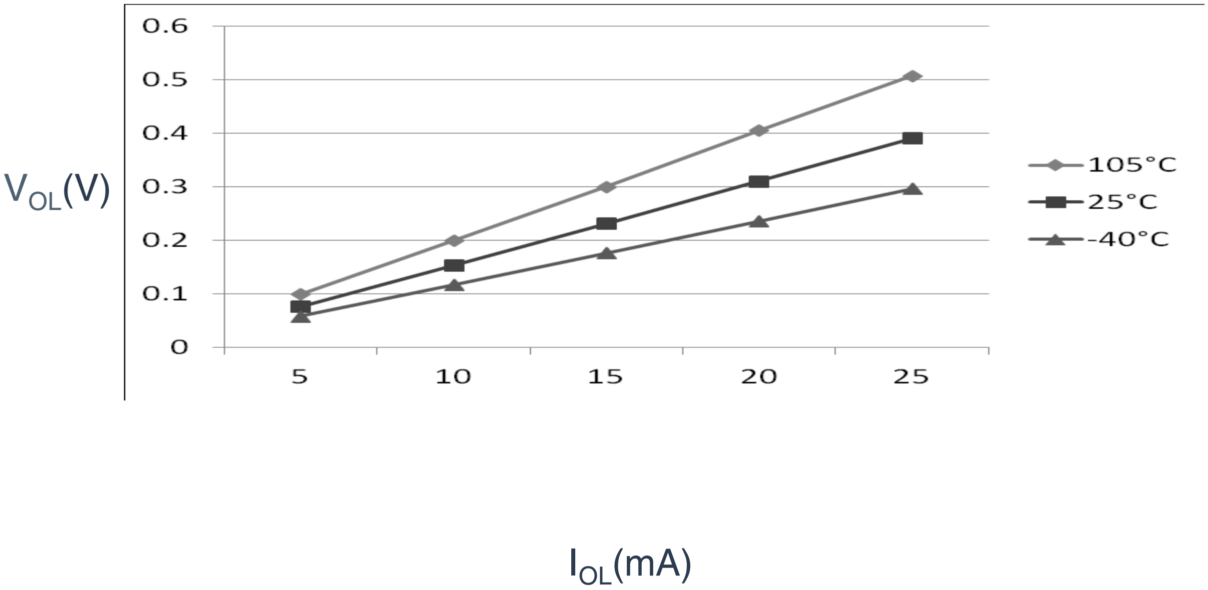


Figure 7. Typical V_{OL} Vs. I_{OL} (high drive strength) (V_{DD} = 5 V)

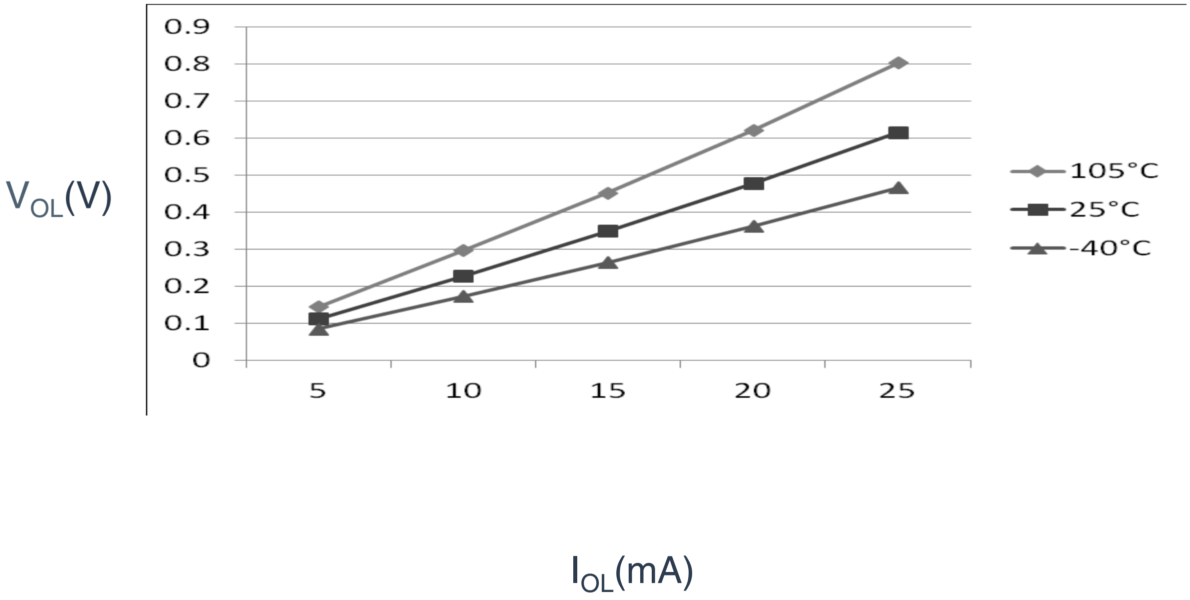


Figure 8. Typical V_{OL} Vs. I_{OL} (high drive strength) (V_{DD} = 3 V)

1. Typical values are based on characterization data at V_{DD} = 5.0 V, 25 °C unless otherwise stated.
2. This is the shortest pulse that is guaranteed to be recognized as a $\overline{\text{RESET}}$ pin request.
3. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized.
4. Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range -40 °C to 105 °C.

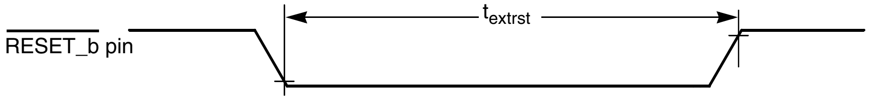


Figure 9. Reset timing

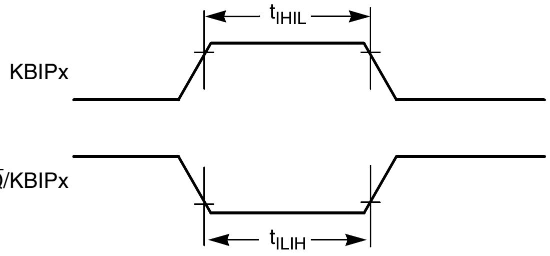


Figure 10. KBIPx timing

5.2.2 FTM module timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 8. FTM input timing

C	Function	Symbol	Min	Max	Unit
D	External clock frequency	f_{TCLK}	0	$f_{Bus}/4$	Hz
D	External clock period	t_{TCLK}	4	—	t_{cyc}
D	External clock high time	t_{clkh}	1.5	—	t_{cyc}
D	External clock low time	t_{clkl}	1.5	—	t_{cyc}
D	Input capture pulse width	t_{ICPW}	1.5	—	t_{cyc}

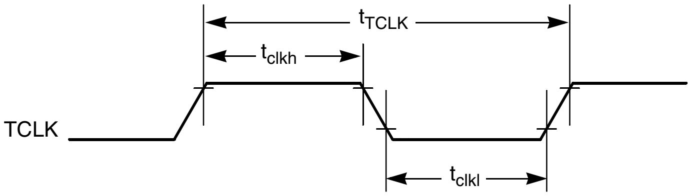


Figure 11. Timer external clock

where K is a constant pertaining to the particular part. K can be determined by measuring P_D (at equilibrium) for an known T_A. Using this value of K, the values of P_D and T_J can be obtained by solving the above equations iteratively for any value of T_A.

6 Peripheral operating requirements and behaviors

6.1 Core modules

6.1.1 SWD electricals

Table 11. SWD full voltage range electricals

Symbol	Description	Min.	Max.	Unit
	Operating voltage	2.7	5.5	V
J1	SWD_CLK frequency of operation • Serial wire debug	0	20	MHz
J2	SWD_CLK cycle period	1/J1	—	ns
J3	SWD_CLK clock pulse width • Serial wire debug	20	—	ns
J4	SWD_CLK rise and fall times	—	3	ns
J9	SWD_DIO input data setup time to SWD_CLK rise	10	—	ns
J10	SWD_DIO input data hold time after SWD_CLK rise	3	—	ns
J11	SWD_CLK high to SWD_DIO data valid	—	35	ns
J12	SWD_CLK high to SWD_DIO high-Z	5	—	ns

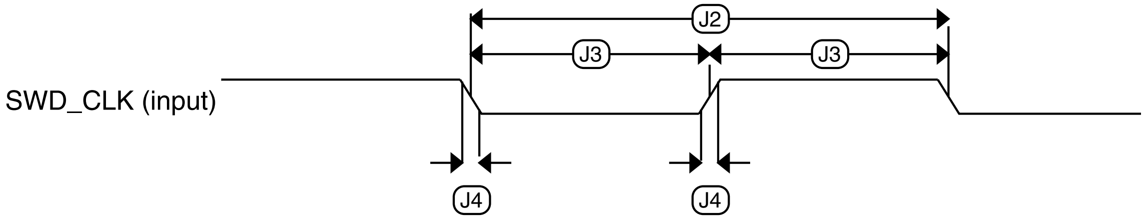


Figure 13. Serial wire clock input timing

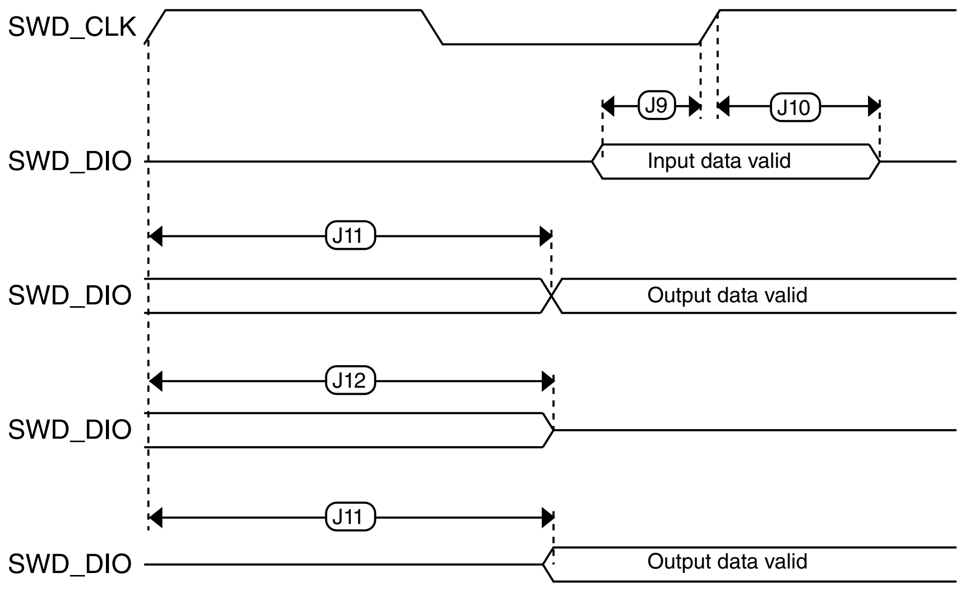


Figure 14. Serial wire data timing

6.2 External oscillator (OSC) and ICS characteristics

Table 12. OSC and ICS specifications (temperature range = -40 to 105 °C ambient)

Num	C	Characteristic		Symbol	Min	Typical[1]	Max	Unit
1	C	Crystal or resonator frequency	Low range (RANGE = 0)	f_{lo}	31.25	32.768	39.0625	kHz
	C		High range (RANGE = 1)	f_{hi}	4	—	20	MHz
2	D	Load capacitors		C1, C2	See Note[2]			
3	D	Feedback resistor	Low Frequency, Low-Power Mode[3]	R_F	—	—	—	MΩ
			Low Frequency, High-Gain Mode		—	10	—	MΩ
			High Frequency, Low-Power Mode		—	1	—	MΩ
			High Frequency, High-Gain Mode		—	1	—	MΩ
4	D	Series resistor - Low Frequency	Low-Power Mode [3]	R_S	—	0	—	kΩ
			High-Gain Mode		—	200	—	kΩ
5	D	Series resistor - High Frequency	Low-Power Mode[3]	R_S	—	0	—	kΩ

Table continues on the next page...

Table 14. 5 V 12-bit ADC operating conditions (continued)

Characteristic	Conditions	Symbol	Min	Typ[1]	Max	Unit	Comment
Input resistance		R_{ADIN}	—	3	5	kΩ	—
Analog source resistance	12-bit mode • $f_{ADCK} > 4$ MHz • $f_{ADCK} < 4$ MHz	R_{AS}	— —	— —	2 5	kΩ	External to MCU
	10-bit mode • $f_{ADCK} > 4$ MHz • $f_{ADCK} < 4$ MHz		— —	— —	5 10		
	8-bit mode (all valid f_{ADCK})		—	—	10		
ADC conversion clock frequency	High speed (ADLPC=0)	f_{ADCK}	0.4	—	8.0	MHz	—
	Low power (ADLPC=1)		0.4	—	4.0		

1. Typical values assume $V_{DDA} = 5.0$ V, Temp = 25°C, f_{ADCK}=1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

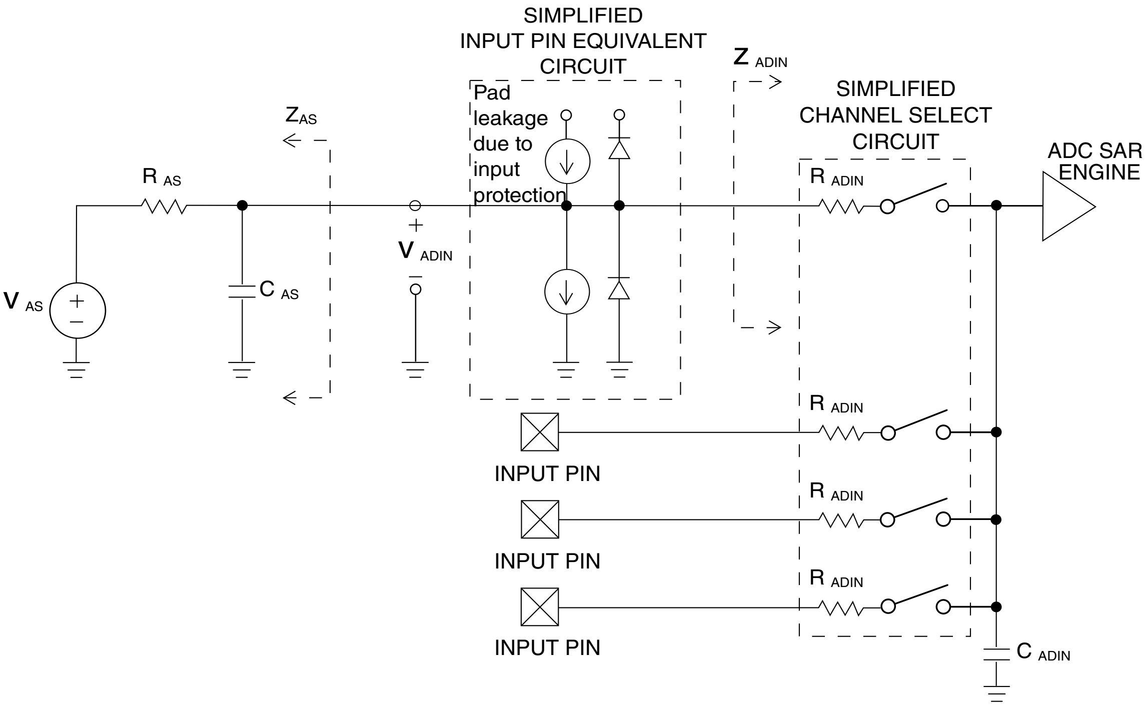


Figure 16. ADC input impedance equivalency diagram

Table 15. 12-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

Characteristic	Conditions	C	Symbol	Min	Typ[1]	Max	Unit
Supply current ADLPC = 1 ADLSMP = 1		T	I_{DDA}	—	133	—	µA

Table continues on the next page...

Table 15. 12-bit ADC characteristics (V_{REFH} = V_{DDA}, V_{REFL} = V_{SSA}) (continued)

Characteristic	Conditions	C	Symbol	Min	Typ[1]	Max	Unit
ADCO = 1							
Supply current ADLPC = 1 ADLSMP = 0 ADCO = 1		T	I_{DDA}	—	218	—	μA
Supply current ADLPC = 0 ADLSMP = 1 ADCO = 1		T	I_{DDA}	—	327	—	μA
Supply current ADLPC = 0 ADLSMP = 0 ADCO = 1		T	I_{DDA}	—	582	990	μA
Supply current	Stop, reset, module off	T	I_{DDA}	—	0.011	1	μA
ADC asynchronous clock source	High speed (ADLPC = 0)	P	f_{ADACK}	2	3.3	5	MHz
	Low power (ADLPC = 1)			1.25	2	3.3	
Conversion time (including sample time)	Short sample (ADLSMP = 0)	T	t_{ADC}	—	20	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	40	—	
Sample time	Short sample (ADLSMP = 0)	T	t_{ADS}	—	3.5	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	23.5	—	
Total unadjusted Error[2]	12-bit mode[3]	T	E_{TUE}	—	±3.6	—	LSB[4]
	10-bit mode	P		—	±1.5	±2.0	
	8-bit mode	T		—	±0.7	±1.0	
Differential Non-Liniarity	12-bit mode	T	DNL	—	±1.0	—	LSB[4]
	10-bit mode[5]	P		—	±0.25	±0.5	
	8-bit mode[5]	T		—	±0.15	±0.25	
Integral Non-Linearity	12-bit mode[3]	T	INL	—	±1.0	—	LSB[4]
	10-bit mode	T		—	±0.3	±0.5	
	8-bit mode	T		—	±0.15	±0.25	
Zero-scale error[6]	12-bit mode	C	E_{ZS}	—	±2.0	—	LSB[4]
	10-bit mode	P		—	±0.25	±1.0	
	8-bit mode	T		—	±0.65	±1.0	
Full-scale error[7]	12-bit mode	T	E_{FS}	—	±2.5	—	LSB[4]
	10-bit mode	T		—	±0.5	±1.0	

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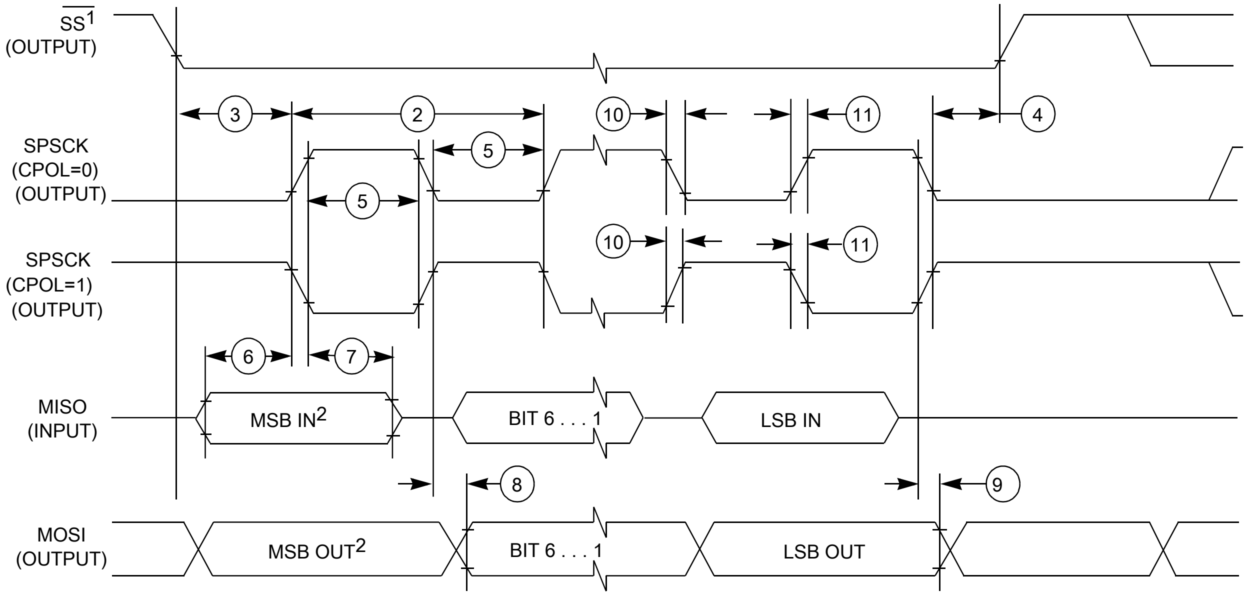
communicating with slower peripheral devices. All timing is shown with respect to 20% V_{DD} and 80% V_{DD}, unless noted, and 25 pF load on all SPI pins. All timing assumes high-drive strength is enabled for SPI output pins.

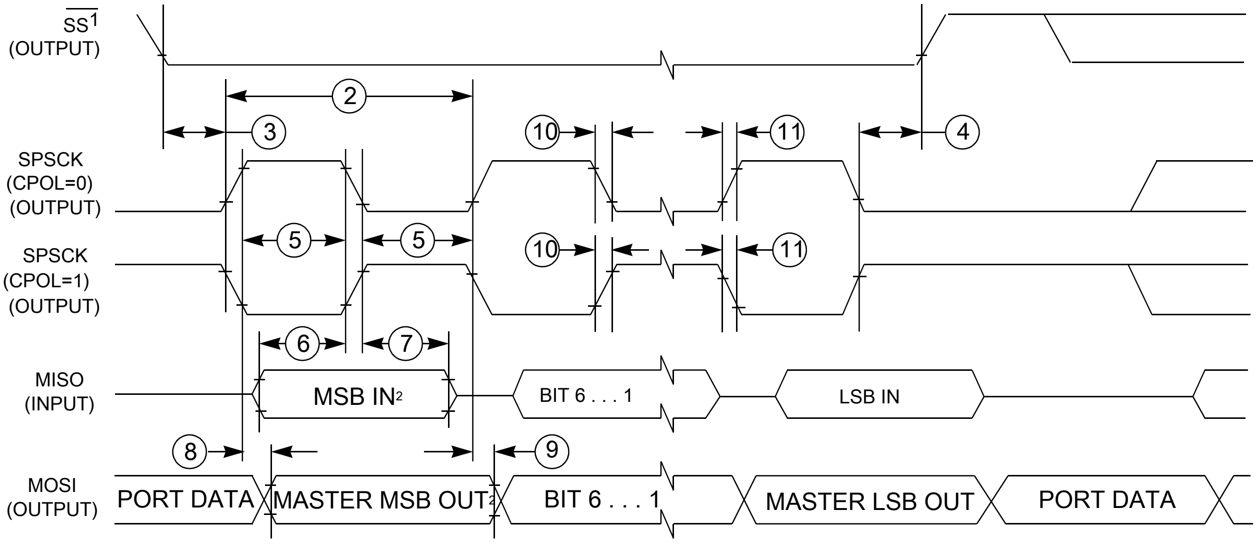
Table 17. SPI master mode timing

Num.	Symbol	Description	Min.	Max.	Unit	Comment
1	f_{op}	Frequency of operation	f_{Bus}/2048	f_{Bus}/2	Hz	f_{Bus} is the bus clock
2	t_{SPSCK}	SPSCK period	2 x t_{Bus}	2048 x t_{Bus}	ns	t_{Bus} = 1/f_{Bus}
3	t_{Lead}	Enable lead time	1/2	—	t_{SPSCK}	—
4	t_{Lag}	Enable lag time	1/2	—	t_{SPSCK}	—
5	t_{WSPSCK}	Clock (SPSCK) high or low time	t_{Bus} – 30	1024 x t_{Bus}	ns	—
6	t_{SU}	Data setup time (inputs)	8	—	ns	—
7	t_{HI}	Data hold time (inputs)	8	—	ns	—
8	t_v	Data valid (after SPSCK edge)	—	25	ns	—
9	t_{HO}	Data hold time (outputs)	20	—	ns	—
10	t_{RI}	Rise time input	—	t_{Bus} – 25	ns	—
	t_{FI}	Fall time input				
11	t_{RO}	Rise time output	—	25	ns	—
	t_{FO}	Fall time output				



1. If configured as an output.
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 17. SPI master mode timing (CPHA=0)



1.If configured as output

2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 18. SPI master mode timing (CPHA=1)

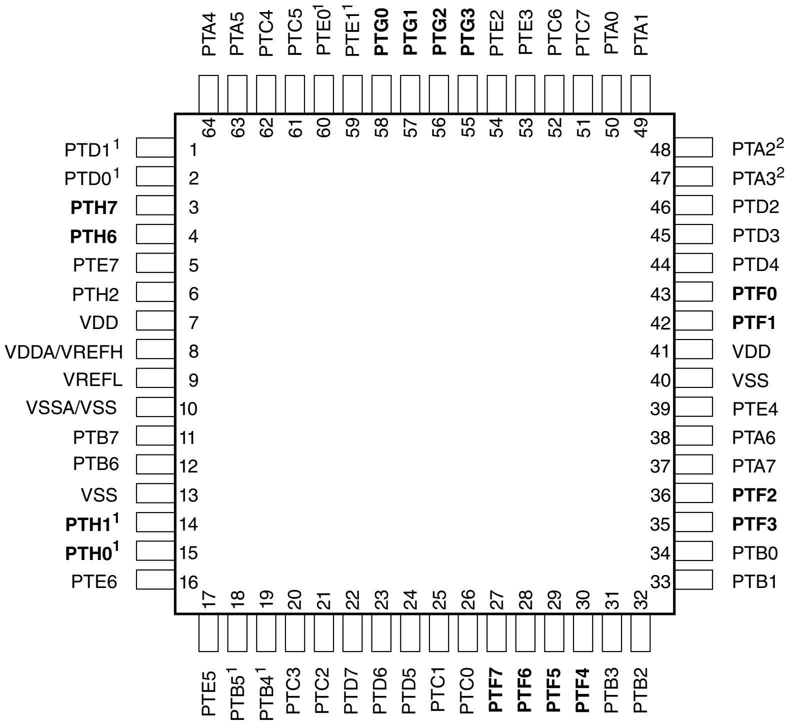
Table 18. SPI slave mode timing

Num.	Symbol	Description	Min.	Max.	Unit	Comment
1	f_{op}	Frequency of operation	0	$f_{Bus}/4$	Hz	f_{Bus} is the bus clock as defined in Control timing.
2	t_{SPSCK}	SPSCK period	4 x t_{Bus}	—	ns	$t_{Bus} = 1/f_{Bus}$
3	t_{Lead}	Enable lead time	1	—	t_{Bus}	—
4	t_{Lag}	Enable lag time	1	—	t_{Bus}	—
5	t_{WSPSCK}	Clock (SPSCK) high or low time	t_{Bus} - 30	—	ns	—
6	t_{SU}	Data setup time (inputs)	15	—	ns	—
7	t_{HI}	Data hold time (inputs)	25	—	ns	—
8	t_a	Slave access time	—	t_{Bus}	ns	Time to data active from high-impedance state
9	t_{dis}	Slave MISO disable time	—	t_{Bus}	ns	Hold time to high-impedance state
10	t_v	Data valid (after SPSCK edge)	—	25	ns	—
11	t_{HO}	Data hold time (outputs)	0	—	ns	—
12	t_{RI}	Rise time input	—	t_{Bus} - 25	ns	—
	t_{FI}	Fall time input				
13	t_{RO}	Rise time output	—	25	ns	—
	t_{FO}	Fall time output				

Table 19. Pin availability by package pin-count (continued)

Pin Number			Lowest Priority <-- --> Highest				
64-QFP/ LQFP	44-LQFP	32-LQFP	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
19	13	10	PTB4[1]	FTM2_CH4	SPI0_MISO	$\overline{\text{NMI}}$	ACMP1_IN2
20	14	11	PTC3	FTM2_CH3	—	—	ADC0_SE11
21	15	12	PTC2	FTM2_CH2	—	—	ADC0_SE10
22	16	—	PTD7	KBI1_P7	UART2_TX	—	—
23	17	—	PTD6	KBI1_P6	UART2_RX	—	—
24	18	—	PTD5	KBI1_P5	—	—	—
25	19	13	PTC1	—	FTM2_CH1	—	ADC0_SE9
26	20	14	PTC0	—	FTM2_CH0	—	ADC0_SE8
27	—	—	PTF7	—	—	—	ADC0_SE15
28	—	—	PTF6	—	—	—	ADC0_SE14
29	—	—	PTF5	—	—	—	ADC0_SE13
30	—	—	PTF4	—	—	—	ADC0_SE12
31	21	15	PTB3	KBI0_P7	SPI0_MOSI	FTM0_CH1	ADC0_SE7
32	22	16	PTB2	KBI0_P6	SPI0_SCK	FTM0_CH0	ADC0_SE6
33	23	17	PTB1	KBI0_P5	UART0_TX	—	ADC0_SE5
34	24	18	PTB0	KBI0_P4	UART0_RX	—	ADC0_SE4
35	—	—	PTF3	—	—	—	—
36	—	—	PTF2	—	—	—	—
37	25	19	PTA7	—	FTM2_FLT2	ACMP1_IN1	ADC0_SE3
38	26	20	PTA6	—	FTM2_FLT1	ACMP1_IN0	ADC0_SE2
39	—	—	PTE4	—	—	—	—
40	27	—	—	—	—	—	VSS
41	28	—	—	—	—	—	VDD
42	—	—	PTF1	—	—	—	—
43	—	—	PTF0	—	—	—	—
44	29	—	PTD4	KBI1_P4	—	—	—
45	30	21	PTD3	KBI1_P3	SPI1_PCS0	—	—
46	31	22	PTD2	KBI1_P2	SPI1_MISO	—	—
47	32	23	PTA3[4]	KBI0_P3	UART0_TX	I2C0_SCL	—
48	33	24	PTA2[4]	KBI0_P2	UART0_RX	I2C0_SDA	—
49	34	25	PTA1	KBI0_P1	FTM0_CH1	ACMP0_IN1	ADC0_SE1
50	35	26	PTA0	KBI0_P0	FTM0_CH0	ACMP0_IN0	ADC0_SE0
51	36	27	PTC7	—	UART1_TX	—	—
52	37	28	PTC6	—	UART1_RX	—	—
53	—	—	PTE3	—	SPI0_PCS0	—	—
54	38	—	PTE2	—	SPI0_MISO	—	—
55	—	—	PTG3	—	—	—	—
56	—	—	PTG2	—	—	—	—

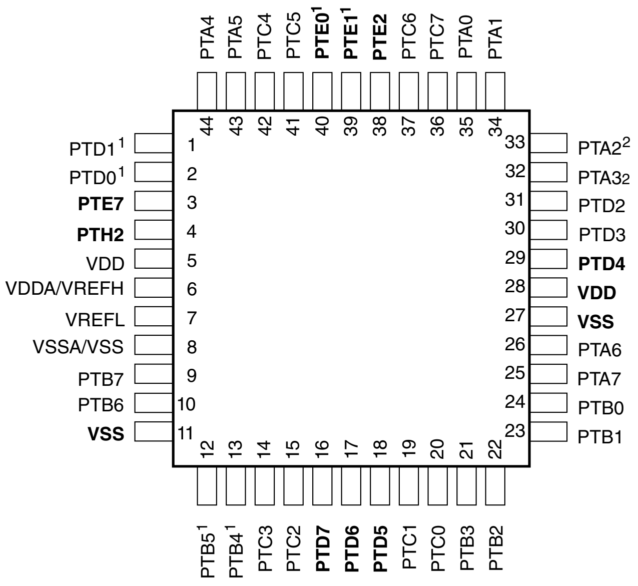
Table continues on the next page...



Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins
2. True open drain pins

Figure 21. 64-pin QFP/LQFP packages



Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins
2. True open drain pins

Figure 22. 44-pin LQFP package

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